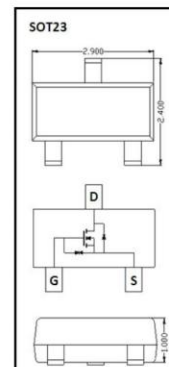
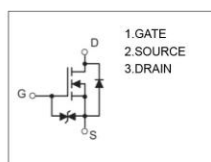


- ◇Epoxy meets UL 94 V-0 flammability rating
- ◇High density cell design for low  $R_{DS(ON)}$
- ◇Voltage controlled small signal switch
- ◇Rugged and reliable
- ◇ESD Protected

Device Marking Code	
2N7002K	72K

Internal Structure


**MAXIMUM RATINGS** ( $T_a = 25\text{ }^\circ\text{C}$ )

Symbol	Parameter	Value	Units
$V_{DS}$	Drain-source Voltage	60	V
$V_{GS}$	Gate-source-Voltage	$\pm 20$	V
$I_D$	Drain Current	340	mA
$P_d$	Total Power Dissipation	300	mW
$T_J$	Junction Temperature	-55 to 150	$^\circ\text{C}$
$T_{JL}$	Storage Temperature	-55 to 150	$^\circ\text{C}$
R	Thermal Resistance from Junction to Ambient	357	$^\circ\text{C}/\text{W}$

**ELECTRICAL CHARACTERISTICS** ( $T_a = 25\text{ }^\circ\text{C}$ )

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
$V_{(BR)DSS}$	Drain-source Voltage Breakdown Voltage	$V_{GS}=0V, I_D=10\mu\text{A}$	60			V
$V_{GS(th)}$	Gate-Threshold Voltage (note 1)	$V_{DS}=V_{GS}, I_D=1\text{mA}$	1.0		2.5	V
$I_{GSS}$	Gate-body Leakage	$V_{DS}=0V, V_{GS}=\pm 10V$			$\pm 200$	nA
		$V_{DS}=0V, V_{GS}=\pm 5V$			$\pm 100$	nA
		$V_{DS}=0V, V_{GS}=\pm 20V$			10	$\mu\text{A}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS}=48V, V_{GS}=0V$			1	$\mu\text{A}$
$R_{DS(on)}$	Drain-source On-resistance (note 1)	$V_{GS}=4.5V, I_D=200\text{mA}$			5.3	$\Omega$
		$V_{GS}=10V, I_D=500\text{mA}$			5.0	$\Omega$
$V_{SD}$	Diode Forward Voltage (note 1)	$V_{GS}=0V, I_S=300\text{mA}$			1.5	V

$Q_r$	Recovered charge	$V_{GS}=0V, I_s=300mA, V_R=25V$ $di_s/dt=-100A/\mu s$		30		nC
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**Dynamic Characteristics**

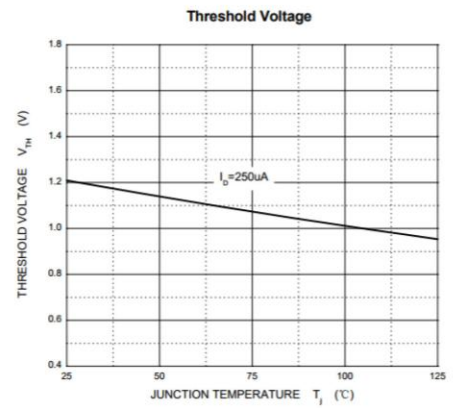
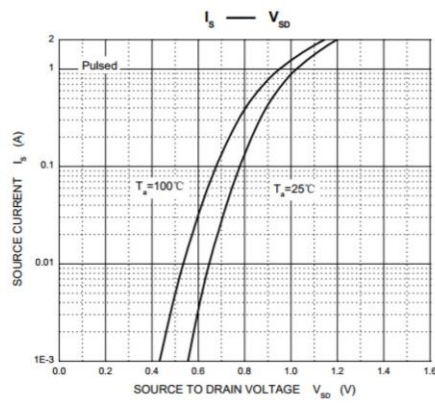
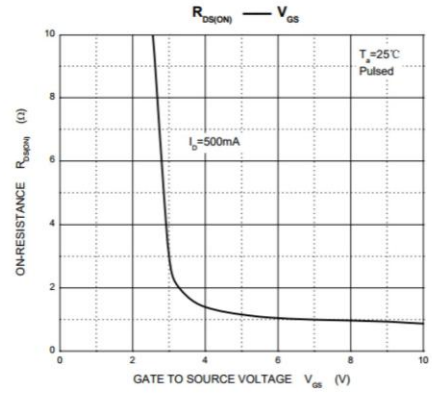
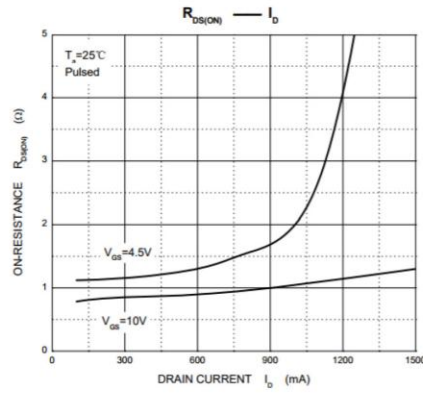
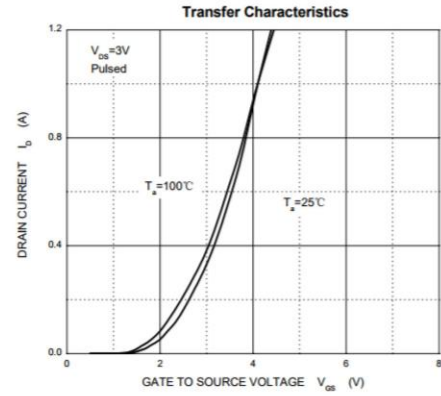
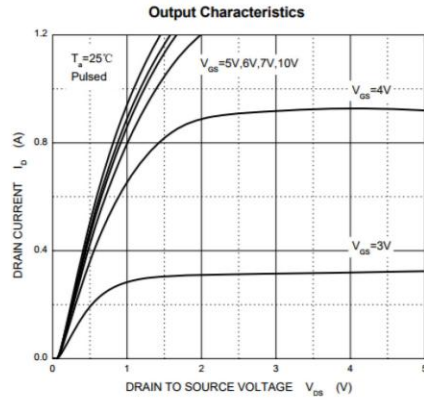
$C_{iss}$	Input Capacitance	$V_{DS}=10V$ $V_{GS}=0V$			40	pF
$C_{oss}$	Output Capacitance				30	
$C_{rss}$	Reverse Transfer Capacitance	$f=1MHz$			10	

**Switching Characteristics**

$t_{d(on)}$	Turn on time	$V_{DD}=50V, R_L=250\Omega$ $R_{GS}=50\Omega, V_{GS}=10V, R_G=50\Omega$			10	ns
$t_{d(off)}$	Turn off time				15	
$t_{rr}$	Reverse recovery time	$V_{GS}=0V, I_s=300mA$ $V_R=25V, di_s/dt=-100A/\mu s$		30		

**Note:**

1. Pulse Test : Pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .

**TYPICAL CHARACTERISTICS**


**ORDERING INFORMATION**

Device	Package	Shipping	Tape wide	Emboss pitch	Tape specification	Notes
2N7002K	SOT23	Tape & Reel 3000pcs /7" Reel	8mm	4mm	Conductive	

**PACKAGE DIMENSIONS**
